

FORM PTO-1449 (Modified)  INFORMATION DISCLOSURE CITATION IN AN APPLICATION  (Use several sheets if necessary)	Docket No. P0284US-7	Application Number 10/676,953
	Applicant LI et al.	
	Filing Date September 30, 2003	Group Art Unit 2826

## U.S. PATENT DOCUMENTS

Examiner Initial	Document Number							Date	Name	Class	Subclass	Filing Date If Appropriate
MLT	5	6	4	4	1	5	6	07/01/97	SUZUKI et al.	257	485	—
MLT	5	3	7	6	2	4	1	12/27/94	SHOR et al.	204	129.3	—

## FOREIGN PATENT DOCUMENTS

	Document Number							Date	Country	Class	Subclass	Translation	
												Yes	No
MLT	JP	07	00	71	79	A		01/10/95	JAPAN				X

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

MLT	1	US 2001/010449 A1 (CHIU CHIEN-CHIA et al) AUGUST 2, 2001.
MLT	2	LAGOUBI, A. et al. "CONDITIONING OF N-SILICON BY PHOTOELECTROCHEMICAL ETCHING FOR PHOTOVOLTAIC APPLICATIONS" PROC. OF THE 11 <sup>TH</sup> E.C. PHOTOVOLTAIC SOLAR ENERGY CONFERENCE, OCTOBER 12, 1992-OCTOBER 16, 1992, pp. 250-253, XP008043956pp 252-253 Figure 8.
MLT	3	PATENT ABSTRACTS OF JAPAN, 07007179, 10-01-95, SANYO ELECTRIC CO LTD, "LIGHT EMITTING ELEMENTZ"

Examiner Minh loan Tran	Date Considered 10/05
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	